

### 1.6X0.8mm SMD CHIP LED LAMP (0.25mm Height)

Part Number: APG1608SEKC/T

Super Bright Orange

#### **Features**

- 1.6mmX0.8mm SMT LED, 0.25mm thickness.
- Low power consumption.
- Wide viewing angle.
- Compatible with automatic placement equipment.
- Ideal for backlight and indicator.
- Package: 2000pcs / reel.
- Moisture sensitivity level : level 3.
- RoHS compliant.

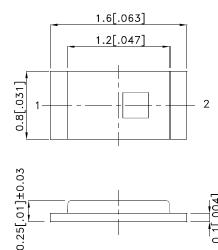
#### Description

The Super Bright Orange device is made with AlGaInP (on GaAs substrate) light emitting diode chip.

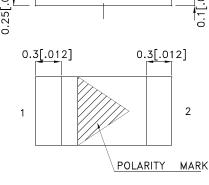
#### **Applications**

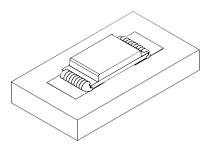
- 1. Mobile phone Keypad indicator and backlight.
- 2.Flat backlight for LCD, switch and symbol.
- 3.Toys.

### **Package Dimensions**









- 1. All dimensions are in millimeters (inches)
- 2. Tolerance is ±0.1(0.004") unless otherwise noted.
- 3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice 4. The device has a single mounting surface. The device must be mounted according to the specifications.

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**REV NO: V.3 CHECKED: Allen Liu**  **DATE: SEP/15/2010** DRAWN: C.H.Han

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#### **Selection Guide**

Part No.	Dice	Lens Type	lv (mcd) [2] @ 20mA		Viewing Angle [1]
		2.	Min.	Тур.	201/2
APG1608SEKC/T	Super Bright Orange (AlGaInP)	Water Clear	120	300	120°

- 1. 01/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.

  2. Luminous intensity/ luminous Flux: +/-15%.

### Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Orange	610		nm	IF=20mA
λD [1]	Dominant Wavelength	Super Bright Orange	601		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Orange	17		nm	IF=20mA
С	Capacitance	Super Bright Orange	15		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Super Bright Orange	2.05	2.5	V	I=20mA
lr	Reverse Current	Super Bright Orange		10	uA	V <sub>R</sub> =5V

#### Notes:

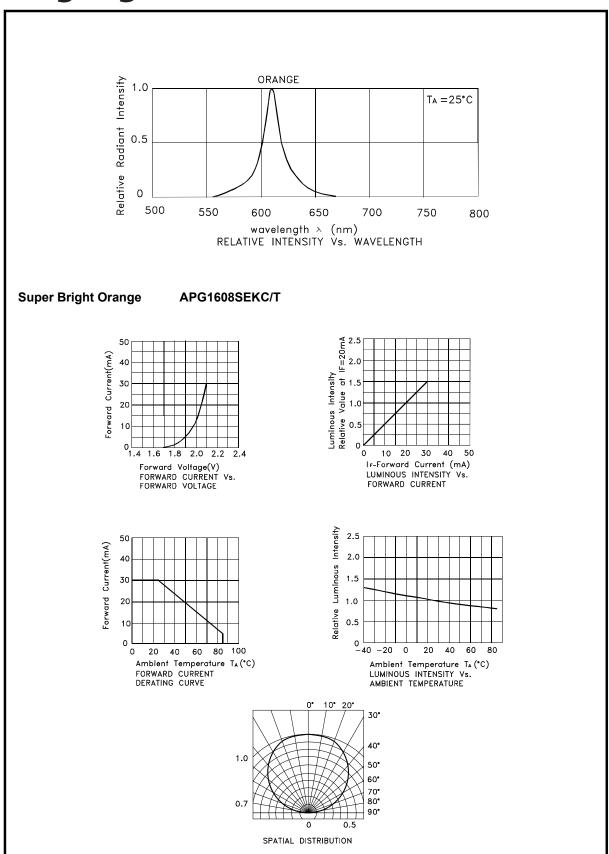
- 1.Wavelength: +/-1nm.
- 2. Forward Voltage: +/-0.1V.

### Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Orange	Units	
Power dissipation	75	mW	
DC Forward Current	30	mA	
Peak Forward Current [1]	150	mA	
Reverse Voltage	5	V	
Operating Temperature	-40°C To +85°C		
Storage Temperature	-40°C To +85°C		

Note: 1. 1/10 Duty Cycle, 0.1ms Pulse Width.

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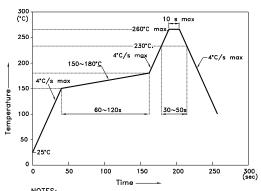


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#### APG1608SEKC/T

Reflow soldering is recommended and the soldering profile is shown below. Other soldering methods are not recommended as they might cause damage to the product.

Reflow Soldering Profile For Lead-free SMT Process.



NOTES:

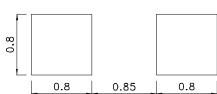
1.We recommend the reflow temperature 245°C(+/-5°C). The maximum soldering temperature should be limited to 260°C.

2.Don't cause stress to the epoxy resin while it is exposed to high temperature.

3.Number of reflow process shall be 2 times or less.

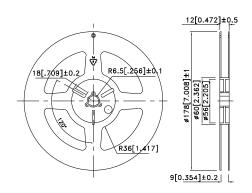
## Recommended Soldering Pattern (Units: mm; Tolerance: ± 0.1)

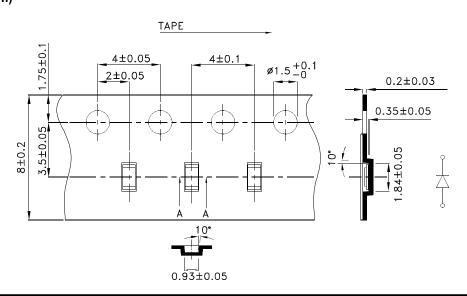
### ints . Inini, Tolerance. ± 0.1)



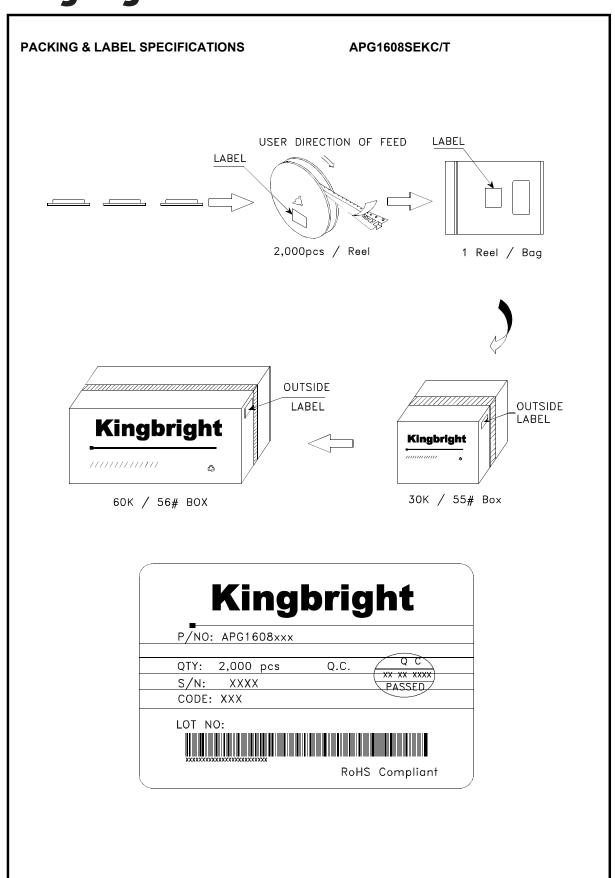
## Tape Dimensions (Units: mm)

#### **Reel Dimension**





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